

2SD1821G

Silicon NPN epitaxial planar type

For high breakdown voltage low-frequency and low-noise amplification

■ Features

- ullet High collector-emitter voltage (Base open) V_{CEO}
- Low noise voltage NV
- S-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing.

■ Absolute Maximum Ratings $T_a = 25$ °C

Symbol	Rating	Unit
V_{CBO}	185	V
V _{CEO}	185	V
V_{EBO}	5	V
I_{C}	50	mA
I_{CP}	100	mA .
P _C	150	mW
T_{j}	150	°C
T _{stg}	-55 to +150	°C (
	$\begin{array}{c} V_{CBO} \\ V_{CEO} \\ V_{EBO} \\ I_{C} \\ I_{CP} \\ P_{C} \\ T_{j} \end{array}$	V _{CBO} 185 V _{CEO} 185 V _{EBO} 5 I _C 50 I _{CP} 100 P _C 150 T _j 150

Package

- Code SMini3-F2
- Marking Symbol: L
- Pin Name
 - 1: Base
- 2: Emitter
- 3: Collector

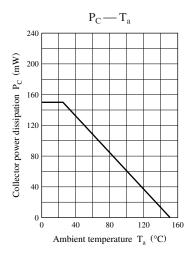
■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

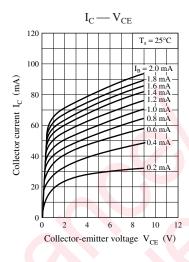
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V_{CEO}	$I_C = 100 \mu A, I_B = 0$	185			V
Emitter-base voltage (Collector open)	V_{EBO}	$I_E = 10 \mu A, I_C = 0$	5			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 100 \text{ V}, I_{E} = 0$			1	μΑ
Forward current transfer ratio *	h _{FE}	$V_{CE} = 5 \text{ V}, I_{C} = 10 \text{ mA}$	130		330	_
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = 30 \text{ mA}, I_B = 3 \text{ mA}$			1	V
Transition frequency	f_T	$V_{CB} = 10 \text{ V}, I_E = -10 \text{ mA}, f = 200 \text{ MHz}$		150		MHz
Collector output capacitance (Common base, input open circuited)	C _{ob}	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		2.3		pF
Noise voltage	NV	$V_{CE} = 10 \text{ V}, I_C = 1 \text{ mA}, G_V = 80 \text{ dB}$ $R_g = 100 \text{ k}\Omega, \text{ Function} = \text{FLAT}$		150		mV

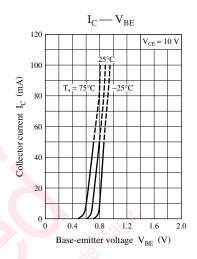
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

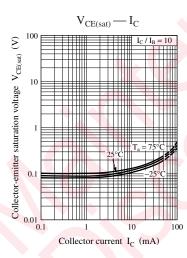
2. *: Rank classification

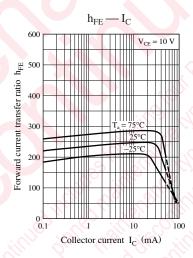
Rank	Q	R
h_{FE}	130 to 220	185 to 330

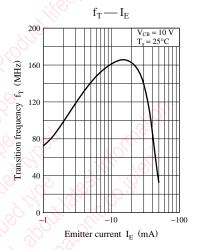


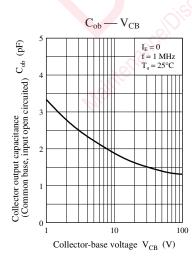




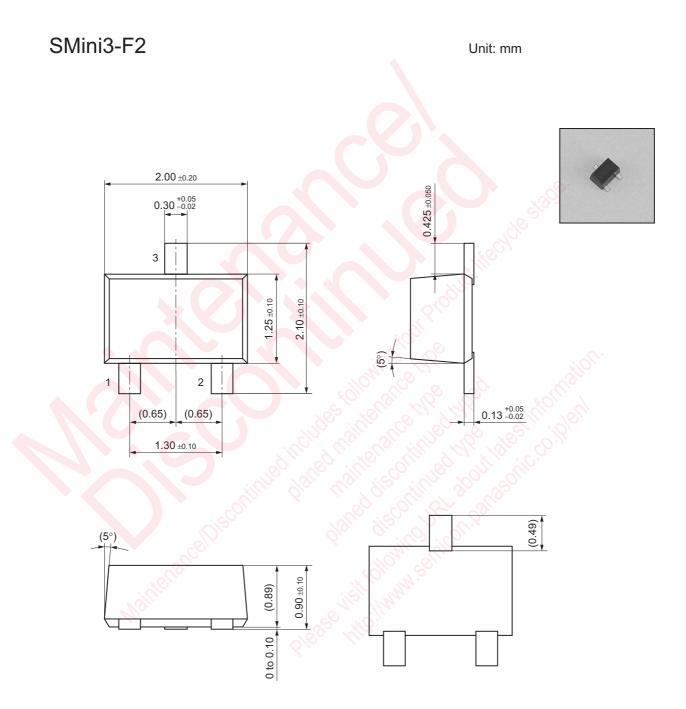








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